Session Program

16-18 Oct 2006

9th RD50 Workshop

Defect and Material Characterization & New Materials

CERN, 40-SS-C01

Monday 16 October

09:45	Defect and Material Characterization & New Materials Session Location: CERN, 40-SS-C01
	09:45-10:05 Results of the simultaneous investigation of the microwave probed photoconductivity and current transients in proton irradiated FZ Si pad detectors
	Speaker Eugenijus Gaubas
	10:05-10:25 Recent results on CdZnTe and SiGe devices
	Speaker Arie Ruzin
	10:25-10:55 Coffee Break
11:25	10:55-11:25 Discussion Session (Defect and Material Characterization & New Materials)